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LUMINESCENCE AND SCINTILLATION PROPERTIES OF Cs3ZnCl5 AND Cs₃ZnCl₅(Eu) SINGLE CRYSTALS

O. Yurchenko*,a, O. Rebrov*,b, V. Cherginets*,c, I. Boyarintseva*,d, T. Rebrova*,e, T. Ponomarenko^{†,f}, O. Lebedinskiy^{‡,g}, O. Zelenskaya^{†,h}

V.N. Karazin Kharkiv National University, School of Chemistry, 4 Svobody sgr., 61022, Kharkiv,

†Institute for scintillation materials of National Academy of Sciences of Ukraine, 60 Nauky Avenue, 61072, Kharkiv, Ukraine

[‡] SSI "Institute for Single Crystals" of NAS of Ukraine, 60, Nauky ave., Kharkiv, 61072, Ukraine

- a) yurchenko@karazin.ua
- b) alrebrov@outlook.com
- c) v_cherginets@ukr.net
- d) gnyavamibigot@gmail.com
- e) tp_rebrova@ukr.net
- f) tv ponomarenko@meta.ua
- g) alexey.lebedinsky@gmail.com
- h) olga.isma@gmail.com

- https://orcid.org/0000-0002-7117-4556
- https://orcid.org/0000-0002-3105-8550
- https://orcid.org/0000-0002-2308-8979
- https://orcid.org/0000-0002-5219-6127
- https://orcid.org/0000-0002-0077-3252
- https://orcid.org/0000-0003-1809-3877 https://orcid.org/0000-0003-2020-9939
- https://orcid.org/0000-0001-7690-1110

This paper reports the results on obtaining and investigation of functional parameters of Cs₃ZnCl₅ crystals grown using Bridgman method from the melts of 3CsCl-2ZnCl2 and 3CsCl-1.995ZnCl2-0.005 EuCl2 compositions. The study of photoluminescence spectra obtained at 237 nm excitation shows the presence of the following emission bands: one at 325 nm caused by the defects or impurities, slightly pronounced band at ca. 450 nm caused by the presence of Eu2+ ions and a series of bands in 590÷700 nm range due to the presence of Eu3+ in the crystals. The presence of said Eu ions is confirmed by the luminescent studies with the use of excitation at wavelengths proper to Eu²⁺ (340 nm) and Eu³⁺ (465 nm). X-ray luminescence spectra include the bands with maxima of 235 nm and 285 nm which are caused by the core-valence luminescence, the band with the maximum at 320 nm caused by the defects and impurities and two bands with the maxima at 400 and 520 nm which nature is not clear (probably, it can be connected with the presence of Eu³⁺ in the samples). The study of light yield performed at the light collection time of 2 µs showed that for all the samples its value is ca. 6% vs. BGO crystal (Bi₄Ge₃O₁₂) and the form of the pulse-height spectra for the crystals grown from both melts practically coincide. This leads to the conclusion that the transfer of excitation from the matrix to Eu²⁺ ions is absent and, according to the photoluminescence studies it can be assumed that Eu2+ exists in the said crystals as inclusions of CsCl:Eu²⁺ solid solution.

Keywords: cesium chloride, zinc chloride, europium chloride, luminescence, scintillation, light vield.

Introduction

The recent progress of material science of halide scintillation materials is connected with the development of rare-earth activated (Eu²⁺, Ce³⁺) simple and complex compounds and their solid solutions. Some of the recently discovered materials are already established trademarks (LaCl₃:Ce³⁺ – BrilLanCeTM350 [1, 2] and LaBr₃:Ce³⁺ – BrilLanCeTM380 [2, 3]) and others (SrI₂:Eu²⁺ [4] and Cs₂LiYCl₆:Ce³⁺ (CLYC) [5]) are efficiently developed and also are commercially available [6,7]. The said materials are solid solutions of halides formed by perfectly isomorphic cations, e.g., LaCl₃:Ce³⁺ means La_{1-x}Ce_xCl₃ and so on.

The search for new activated halide luminescent materials is performed among solid solutions formed by restrictedly isomorphic cations, e.g., for Eu²⁺-activated materials compounds formed by Ca^{2+} [8] and Mg^{2+} [9] have been investigated.

This work presents an attempt to obtain Eu²⁺-activated material on the basis of Cs₃ZnCl₅ compound formed by Zn²⁺ cation restrictedly isomorphic to Eu²⁺. According to [10] the difference of the

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electronegativities of Eu and Zn is 0.4 that is the limiting value for the perfect isomorphism (The Goldschmidt rule), as for the difference of the ionic radii [11] it considerably exceeds 15%.

It should be noted that the said non-activated material is also referred to scintillators for detection of X-ray irradiation [12].

The results of our study are presented below.

Experimental part

Reagents. Extra pure cesium chloride was used for the crystal growth of crystals on the basis of Cs₃ZnCl₅.

Zinc chloride was obtained by the dissolution of metallic zinc of reagent grade in extra pure hydrochloric acid according to well-known routine [13]. Obtained ZnCl₂ was grinded in glow box and kept there.

Charge for the growth of Cs₃ZnCl₅ was prepared by mixing of CsCl with ZnCl₂ in glow box in the mass ratio of 3,71:1.

The charge for the preparation of the growth melt of Cs₃ZnCl₅ melt with addition of 0.5 mol. % of Eu²⁺ with respect to Zn²⁺ was prepared in such a manner. Primarily solid solution of CsCl-EuCl₂ composition was prepared by the dissolution of 0.0882 g of Eu₂O₃ in 50 g of molten CsCl by the carbohalogenation process at 700 °C:

$$2 E u_2 O_3 \downarrow +3 C C l_4 = 4 E u C l_2 +3 C O_2 \uparrow +2 C l_2 \uparrow$$
 (1)

The primarily formed suspension of Eu₂O₃ disappeared after 1h treatment the melt became transparent and further it was treated for 1 h, cooled, grinded and kept in glow box. The temperature of the carbohalogenation provided practically complete reduction of EuCl₃ into EuCl₂.

For the preparation of Cs₃ZnCl₅:0.5 mol. % of Eu²⁺ charge 19.72 g of CsCl:Eu²⁺ powder was mixed in the glow box with 5.282 g of ZnCl₂.

The growth procedure. The charge was placed in quartz ampoule of 12 mm diameter and 500 mm height. Before the growth the ampoule with the charge was kept under vacuum (1 Pa) for 24 h at 700 °C.

The growth of the crystals was performed by Bridgman method in two-zone furnace, the difference of temperature between the zones was 80 °C, temperature gradient was ca. 40 °C/cm, the rate of the dropping of the ampoule was 3.2 mm/h. After the finishing of the ampoule broaching the furnace was cooled to room temperature during 72 h.

After the cooling, ampoule was placed in the glow box where it was broken down and the ingot was removed. The transparent part of the ingot was cut, polished and kept in polyethylene batch in the glow box. The samples presented cylinders of $6 \div 10$ mm diameter and 1 mm height.

The obtained samples were practically non-hygroscopic, therefore, they were not packed into containers at all the investigations.

Investigation of the obtained samples. The phase composition of the parts of the obtained ingot was determined using X-ray diffractometer DRON with Cu-K α radiation.

The study of luminescent properties of the obtained samples was performed using a combined fluorescent lifetime and steady-state spectrometer FLS 920 (Edinburgh Instruments) equipped with a xenon Xe 450 W and hydrogen filled nF 900 nanosecond flashlamp for time correlated single photon counting measurements. Photoluminescence excitation (PLE) spectra were corrected on the incident photon flux. Photoluminescence emission (PL) spectra were corrected for the spectral sensitivity of the detection system.

The spectra of X-ray excited luminescence were obtained under X-ray (Cu, 40 kV, 40 μ A) excitation in transmission mode and were not corrected for the spectral sensitivity of the detection system.

Scintillation decay time profiles of Cs₃ZnCl₅-based samples were obtained as follows. The samples were placed on the photocathode of Hamamatsu R6231 PMT. Scintillations were excited with 662 keV gammas from ¹³⁷Cs source. Signal from PMT anode was fed to the input of Rigol DS6064 oscilloscope. Decay curves were calculated by averaging of several hundreds of recorded pulses with amplitudes approximately corresponding to the full absorption peak.

The light yield and the energy resolution of the obtained samples were determined by the method of comparison [14]. The measurements were recorded using a pulse processing chain consisting of an

R1307 SU 0192 PMT (Hamamatsu, Japan), a charge-sensitive preamplifier BUS 2-95, a custom shaping amplifier and a multichannel analyzer AMA-03F. Relative light yield was determined by comparing the peak position (abscissa) of the grown crystals and that of a BGO ($Bi_4Ge_3O_{12}$) crystal (10,000 photons/MeV and energy resolution of 10 %). All measurements were done under the same conditions using the shaping time of 8 μ s. The error of the light yield and energy resolution measurements was less than 5 %.

Results and discussion

As it was mentioned in the previous section all the ingots consisted of lower opaque part and upper transparent one. Taking into account that Eu^{2+} is slightly isomorphic to Zn^{2+} we performed examination of both parts of the ingot. The X-ray diffraction patterns of the said samples coincide.

The X-ray diffraction pattern of the samples grown from Cs₃ZnCl₅ melt containing EuCl₂ is presented in Fig. 1. It is seen that the ingots consist of Cs₃ZnCl₅ (tetragonal unit cell, a=0.926 nm, c=1.450 nm, space group I4/mcm) [15].

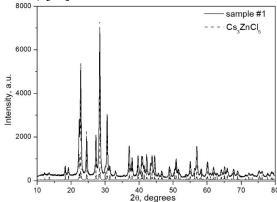


Figure 1. The X-ray diffraction pattern of the sample grown from Cs₃ZnCl₅ (Eu) melt (thick line) and the database data for Cs₃ZnCl₅ (thin line)

It means that there was no selective accumulation in the opaque part of CsCl or its compounds with EuCl₂ of CsEuCl₃ composition (tetragonal unit cell, a=0.5588(4) nm, c=0.5619(8) nm, space group P4 mm) [16]. It may be concluded that Eu²⁺ is distributed throughout all the ingot.

The excitation and photoluminescence spectra of the transparent part of the sample are presented in Fig. 2.

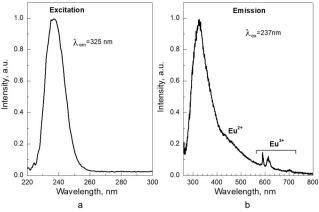


Figure 2. Excitation (a, λ_{em} =325 nm) and emission (b, λ_{ex} =237 nm) spectra of sample grown from Cs₃ZnCl₅ (Eu)

It can be seen that the main luminescence band at excitation wavelength of 237 nm is placed at 310 nm. Authors [12] found that similar band with the emission band 290 nm was obtained under excitation at $70\div90$ nm and it was ascribed to Auger-free luminescence (AFL). In [17] the same authors studied luminescence of crystals of $Cs(Ca_{1-x}Mg_x)Cl_3$ composition and found that at the excitation at 240 nm the luminescence for all the studied materials is observed in $350\div390$ nm range. Taking into account the excitation wavelength (240 nm) the authors assumed that this luminescence is

caused by defects or impurity sites. It is very probable that the emission band at 310 nm is also due to impurities or defects. The decay profile for the luminesce excited at 237 nm is monoexponential and the decay constant is estimated as 260 ns.

The beside of the above-discussed band in the emission spectra there is also the band proper to Eu^{2+} (~430 nm, slightly pronounced) and Eu^{3+} (three bands in 590÷700 nm region).

To check whether the 430 nm band is caused by the presence of Eu²⁺ we recorded the photoluminescence spectra using excitation at 340 nm proper for Eu²⁺. These spectra are shown in Fig. 3

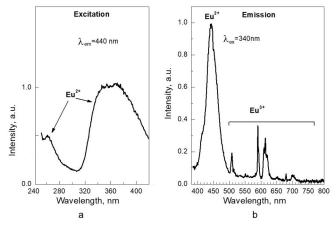


Figure 3. Excitation (a, λ_{em} =440 nm) and emission (b, λ_{ex} =340 nm) spectra of sample grown from Cs₃ZnCl₅ (Eu) melt

The excitation spectrum includes bands at 260 nm and wide band at 330÷400 nm that is proper to excitation of Eu²⁺ ions and the emission band at 442 nm. We can assume that the 442 nm band can be ascribed to the formation of CsCl:Eu²⁺ solid solution since the same wavelength was obtained by the authors of [18].

As for the luminescence decay curve, it is presented in Fig. 4 and can be described by three components with decay constants of 17, 68 and 360 ns.

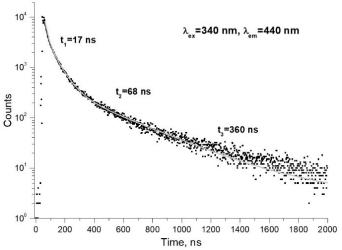


Figure 4. The decay curve (λ_{ex} =340 nm, λ_{em} =440 nm) for the sample grown from Cs₃ZnCl₅ (Eu) melt

It is interesting that authors [18] estimated the decay constant of longer component as 360 nm. As for the presence in the sample of Eu³⁺, it is easily confirmed by the data of Fig. 5.

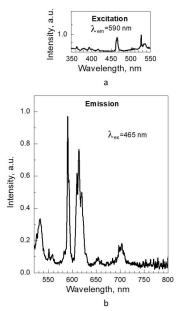


Figure 5. Excitation (a, λ_{em} =590 nm) and emission (b, λ_{ex} =465 nm) spectra of sample grown from Cs₃ZnCl₅ (Eu) melt

The emission spectrum includes bands at 590, 612 and 700 nm which are referred to luminescence of Eu³⁺. So, at least the traces of EuCl₃ are present in the sample. This is proper to other chloride materials doped with Eu²⁺ since the decomposition temperature of EuCl₃ to EuCl₂ is close to 700 °C and even long-term keeping of the growth melt under vacuum does not provide the complete decomposition of EuCl₃ to EuCl₂.

Now let us consider results connected with the scintillation properties of the obtained crystals. The X-ray luminescence spectrum is presented in Fig. 6.

According to [12] the bands with maxima of 235 nm and 285 nm can be referred to core-valence luminescence, the band with the maximum at 320 nm according to the description of Fig. 1 is caused by the defects and impurities. As for the band with the maximum at 520 nm its nature is unknown, it may be caused by the presence of Eu³⁺ in the samples.

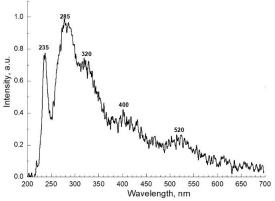


Figure 6. X-ray luminescence spectrum of sample grown from Cs₃ZnCl₅ (Eu) melt (reflectance mode, silver anode, I=40 µA, U=40 kV)

As for the light yield and energy resolution the light collection time of 2 µs was chosen going from the luminescence decay constants, the pulse-height spectra of the obtained crystals are presented in Fig. 7.

From Fig. 7a it follows that the light yield of Cs₃ZnCl₅(Eu) is equal to 5.8 % against BGO, i.e., *ca*. 580 photons per MeV. As for undoped Cs₃ZnCl₅ its light yield achieves 6 % against BGO (600 photons MeV), that agrees with the data of [12]. Due to complex structure of the photopeaks of the obtained crystals (Fig. 7b) any estimations of the energy resolution would be incorrect.

So, the light yield of Cs₃ZnCl₅ is not dependent on the presence or absence of Eu²⁺ ions in the sample and the pulse-height spectra are identical (Fig.7b). It means that the transfer of the excitation from matrix to Eu²⁺ ion is negligible or absent due to restricted isomorphism of Eu²⁺ and Zn²⁺ ions, which is confirmed by the data of Fig. 6. The most possible form of Eu²⁺ existence in the grown crystals considered in this paper may be CsCl:Eu²⁺ inclusions or traces of CsEuCl₃ (see Fig. 3 and description for it).

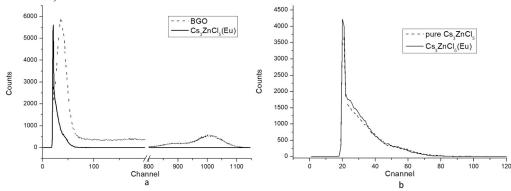


Figure 7. Pulse height spectra of: 1 − Cs₃ZnCl₅:(Eu) sample vs. BGO (Bi₄Ge₃O₁₂, standard), 2 − a comparison of the spectra for undoped Cs₃ZnCl₅ and Cs₃ZnCl₅ :(Eu)

Conclusions

In this study crystals on the basis of Cs₃ZnCl₅ were grown by Bridgman method from the melts of 3CsCl-2ZnCl₂ and 3CsCl-1.995ZnCl₂-0.005 EuCl₂ compositions.

The luminescence spectra of the Cs_3ZnCl_5 samples obtained at λ_{ex} =237 nm include bands caused by defects or admixtures (325 nm), Eu^{2+} ions (450 nm) and Eu^{3+} ions (in the range of 590÷700 nm). The presence of both Eu ions was confirmed by luminescence investigations at excitation at wavelengths proper for the corresponding ions. The X-ray luminescence spectra did not include the bands proper for Eu ions.

The study of light yield performed at the light collection time of 2 μ s showed that the light yield of the crystals grown from both melts is ca. 6% ν s. BGO (Bi₄Ge₃O₁₂) and the shapes of the pulse-height spectra are practically the same that confirms the negligible excitation transfer from the matrix to Eu²⁺ ions. Taking into account the results of photoluminescence studies it can be assumed that Eu²⁺ ions exist in the grown Cs₃ZnCl₅ crystals as inclusions of CsCl:Eu²⁺ solid solution.

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О. І. Юрченко † , О. Л. Ребров † , В. Л. Чергинець † , Я. А. Бояринцева † , Т. П. Реброва † , Т. В. Пономаренко † , О. М. Лебединський † , О. В. Зеленська † . Люмінесцентні і сцинтиляційні властивості монокристалів кристалів Cs₃ZnCl₅ та Cs₃ZnCl₅(Eu).

^{*}Харківський Національний університет ім. В.Н. Каразіна, хімічний факультет, пл. Свободи, 4, 61022, Харків, Україна

[†]Інститут сцинтиляційних матеріалів Національної академії наук України, пр. Науки, 60, 61072, Харків, Україна

[‡]НТК "Інститут монокристалів" Національної академії наук України, пр. Науки, 60, 61072, Харків, Україна

Наведено результати робіт з отримання і дослідження функціональних властивостей кристалів Cs_3ZnCl_5 , вирощених з розплавів складів $3CsCl-2ZnCl_2$ і $3CsCl-1.995ZnCl_2-0.005$ $EuCl_2$. У спектрах фотолюмінесценції кристалів, одержаних при λ_{em} =237 нм, спостерігається смуга з максимумом при 325 нм, яка може бути обумовлена наявністю дефектів і домішок, слабка смуга при ~450 нм, що відноситься до люмінесценції Eu^{2+} , а також серія смуг в інтервалі 590-700 нм, які відносяться до люмінесценції Eu^{3+} . Присутність іонів європію Eu було доведено дослідженнями люмінесценції при збудженні на довжинах хвиль притаманних для Eu^{2+} (340 нм) і Eu^{3+} (465 нм). Спектри рентгенолюмінесценції містять смуги з максимумами при 235 нм і 285 нм, що відповідають остовно-валентній люмінесценції, при 320 нм (можливо, дефекти і домішки) і дві смуги з максимумами при 400 і 520 нм, природа яких не з'ясована (можливо, вони пов'язані з присутністю іонів Eu^{3+} у зразках). Дослідження світлового виходу одержаних кристалів, проведені при часі світлозбирання 2 мкс, показали, що кристали обох складів мають світловихід приблизно 6% відносно кристалів BGO ($Bi_4Ge_3O_{12}$), а форма їх амплітудних спектрів практично однакова, що свідчить про незначний перенос збудження від матриці до іонів Eu^{2+} . Виходячи з результатів дослідження фотолюмінесценції, можна припустити, що Eu^{2+} існує у вирощених кристалах у вигляді включень твердого розчину $CsCl:Eu^{2+}$.

Ключові слова: хлорид цезію, хлорид цинку, хлорид європію, люмінесценція, сцинтиляційні властивості, світловий вихід.

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